# NSN 5962-01-535-6003

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# **Features Provided:**

Electrostatic sensitive and ultraviolet erasable and monolithic and programmable

# **Inclosure Material:**

Ceramic

# Inclosure Configuration:

Dual-in-line

# **Output Logic Form:**

Complementary-metal oxide-semiconductor logic

# Memory Device Type:

Pal

# Terminal Type And Quantity:

24 printed circuit

#### Shelf Life:

N/a

### Unit Of Measure:

--Demilitarization:

Yes - demil/mli

# Fiig:

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